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Interface Engineering V$_2$O$_5$ Nanofibers for High-Energy and Durable Supercapacitors

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A local electric field is induced to engineer the interface of vanadium pentoxide nanofibers (V$_2$O$_5$-NF) to manipulate the charge transport behavior and obtain high-energy and durable supercapacitors. The interface of V$_2$O$_5$-NF is modified with oxygen vacancies (V$_6$O$_7$) in a one-step polymerization process of polyaniline (PANI). In the charge storage process, the local electric field deriving from the lopsided charge distribution around V$_6$O$_7$ will provide Coulombic forces to promote the charge transport in the resultant V$_6$O$_7$-V$_2$O$_5$/PANI nanocable electrode. Furthermore, an ~7 nm porous PANI coating serves as the external percolated charge transport pathway. As the charge transfer kinetics are synergistically enhanced by the dual modifications, V$_6$O$_7$-V$_2$O$_5$/PANI-based supercapacitors exhibit an excellent specific capacitance (523 F g$^{-1}$) as well as a long cycling lifespan (110% of capacitance remained after 20,000 cycles). This work paves an effective way to promote the charge transfer kinetics of electrode materials for next-generation energy storage systems.

1. Introduction

Developing devices to store energy conveniently, controllably and sustainably is critical to solve issues of energy crisis and environmental pollution.[1] Supercapacitors have emerged as highly efficient and promising energy storage devices in intermittent renewable energy sources, smart power grids, and electrical vehicles, due to the higher power density, longer durability and safety over traditional fuel cells and batteries.[2] Great efforts have been made on elaborating the electrode materials with higher energy density for supercapacitors to meeting ever-increasing requirements. The energy density (E) of a supercapacitor is mainly dependent on the specific capacitance (C) and cell potential window (V) of electrode materials according to the equation $E = 1/2CV^2$.[3] Thus, developing electrode materials with enhanced specific capacitance is crucial for high-energy supercapacitors. Carbonaceous material based electric double-layer capacitors appear with a low capacitance due to the physical adsorption/desorption at the electrode surface.[8] Comparatively, transition metal oxides (TMOs) and conductive polymers (CPs) based pseudocapacitors exhibit higher theoretical storage capacitance because of the reversible faradic reactions on or near the electrode surface.[9]

Vanadium pentoxide (V$_2$O$_5$), a layer-structured TMO, has prospective applications in electrochemical energy storage due to its high theoretical capacitance (2020 F g$^{-1}$), a broader operating voltage (up to ~2.8 V), as well as low cost and abundance in nature.[6] However, the poor electrical conductivity of V$_2$O$_5$ (10$^{-3}$ to 10$^{-2}$ S cm$^{-1}$) limits the electron transfer kinetics for redox reactions. As a result, the pseudocapacitive reactions mainly occur on the surface or near-surface region of V$_2$O$_5$ electrode materials, leading to a low utilization of V$_2$O$_5$ and unsatisfactory specific capacitance.[7] In addition, the vanadium dissolution and structural instability reduces its cycling life.[8]

To address these problems, many synthetic methods have been proposed. First, nanostructured V$_2$O$_5$ materials with a large specific surface area are fabricated to provide sufficient contact area for fast Faradic reactions, such as nanoribbons,[9] and nanobelts.[10] Second, tailoring the materials with multiple physicochemical properties can effectively enhance the electrochemical performance of V$_2$O$_5$ with diverse functions from components. For instance, layered V$_2$O$_5$/poly(3,4-ethylenedioxythiophene) (PEDOT)/MnO$_2$ nanosheets show enhanced energy density (39.2 W h kg$^{-1}$) and cycling stability (93.5% capacitance retention after 3000 cycles) due to the synergistic combination of PEDOT, MnO$_2$, and V$_2$O$_5$.[11] However, V$_2$O$_5$ electrode materials with enhanced electrochemical performance, fabricated in an uncomplicated and low-cost process are still necessary for practical applications. Based on the previous study, both polyaniline (PANI) and PEDOT improve the electrical conductivity as well as the stability of V$_2$O$_5$ by forming a conductive coating.[8,11]
while PANI has the advantage of easier preparation and lower aniline monomer cost (3.6 $ mL\textsuperscript{-1}) over EDOT monomers (9.6 $ mL\textsuperscript{-1}), which can be found in supporting information. Defects, especially oxygen vacancies (V\textsubscript{ö}), have been reported to intrinsically enhance the charge transfer kinetics and cycling performance of V\textsubscript{2}O\textsubscript{5} by modifying its surface chemistry and electronic properties\textsuperscript{[12]} Therefore, it would be significant to improve the electrochemical performance of V\textsubscript{2}O\textsubscript{5} by rationally integrating PANI and V\textsubscript{ö} into nanostructured V\textsubscript{2}O\textsubscript{5} with an easy and simple method.

In this work, nanofiber-like V\textsubscript{2}O\textsubscript{5} (V\textsubscript{2}O\textsubscript{5}-NF) are engineered with V\textsubscript{ö} and PANI at the surface region through one-step in situ oxidatively polymerization of aniline monomers. In the resultant V\textsubscript{ö}-V\textsubscript{2}O\textsubscript{5}/PANI nanocables, a local electric field is induced and provides Coulombic forces to promote the ion diffusion due to unbalanced charge distribution caused by V\textsubscript{ö}. The porous PANI shell offers an external percolated pathway for fast charge transport. The enlarged surface area also benefits redox reactions with a larger contact area. Thus, the charge transfer kinetics is enhanced by the interface modifications of V\textsubscript{ö} and PANI. Consequently, V\textsubscript{ö}-V\textsubscript{2}O\textsubscript{5}/PANI electrode manifests an excellent specific capacitance, energy density as well as a superior cycling life.

2. Results and Discussion
As shown in Figure 1a, the Fourier transform infrared (FTIR) spectrum of as-prepared V\textsubscript{ö}-V\textsubscript{2}O\textsubscript{5}/PANI shows the characteristic peaks of PANI at 1634 cm\textsuperscript{-1} (the stretching of quinoid rings overlaps with the band caused by structural water), 1587, 1502 (the aromatic C–C stretching, C–H in-plane bending modes), 1300 cm\textsuperscript{-1} (C–N stretching of secondary aromatic amine), and 692 and 633 cm\textsuperscript{-1} (the aromatic ring and out-of-plane deformation vibrations).\textsuperscript{[13,14]} The V=O stretching bond at 1021 cm\textsuperscript{-1}, and V–O stretching vibration at 854, 615, 530, and 417 m\textsuperscript{-1} belong to V\textsubscript{2}O\textsubscript{5}. The V\textsubscript{ö}-V\textsubscript{2}O\textsubscript{5}/PANI was further investigated by means of Raman spectrometry. As shown in Figure S2a (Supporting Information), the Raman spectrum displayed peaks of V\textsubscript{2}O\textsubscript{5}-NF at 146, 286, 405, 484, 528, 703, and 995 cm\textsuperscript{-1}, corresponding to bending vibrations of V–O–V, V=O and

![Figure 1.](image-url)
bridge oxygen bonds, the stretching vibrations of chain oxygen and doubly coordinated oxygen, and in-plane stretching vibrations of V=O bonds, respectively.\(^{(2)}\) For V\(_6\)V\(_2\)O\(_5\)/PANI, the bands at 1240, 1349, 1403, and 1564 cm\(^{-1}\) belong to in-plane C–H bending of the benzenoid ring, C–N\(^\equiv\) stretching, C=C stretching of quinoid ring and benzenoid ring, indicating the existence of doped PANI in V\(_6\)V\(_2\)O\(_5\)/PANI.\(^{(13)}\)

Thermogravimetric and differential scanning calorimetric (TG-DSC) measurements of V\(_6\)V\(_2\)O\(_5\)/PANI present a thermal degradation of PANI with ≈40% weight lost between 120 and 400 °C in Figure 1b.\(^{(16)}\) An initial ≈3.5% mass loss is mainly caused by the release of adsorbed water, and the endothermic peak at around 675 °C is caused by V\(_2\)O\(_5\).

Nitrogen sorption isotherms and pore size distributions of V\(_6\)V\(_2\)O\(_5\)/PANI and V\(_2\)O\(_5\)-NF are shown in Figure 1c and Figure S2b (Supporting Information), respectively. V\(_6\)V\(_2\)O\(_5\)/PANI displays a porous structure (micropores, mesopores, and macropores) with a larger specific surface area of 58 m\(^2\) g\(^{-1}\) and V\(_2\)O\(_5\)-NF (38 m\(^2\) g\(^{-1}\)). The increase in specific surface area should be attributed to the porous PANI layer, which can serve as an external percolated pathway for charge transport in the charging and discharging process. This increased surface area is expected to provide more active sites for redox reactions, facilitating the charge storage in supercapacitors.

In the X-ray diffraction (XRD) patterns (Figure 1d), V\(_6\)V\(_2\)O\(_5\)/PANI shows a pure V\(_2\)O\(_5\) phase, which can be indexed to JPD No. 85-0601. Compared with V\(_2\)O\(_5\)-NF, the decreased peak intensity of V\(_6\)V\(_2\)O\(_5\)/PANI suggests lower crystallinity degree in V\(_6\)V\(_2\)O\(_5\)/PANI, which could be caused by V\(_6\) and PANI.

Figure 1e presents the V 2p X-ray photoelectron spectroscopy (XPS) spectra of V\(_6\)V\(_2\)O\(_5\)/PANI with two main peaks of V 2p\(_{1/2}\) and V 2p\(_{3/2}\) at ≈524.4 and ≈517.1 eV, respectively. Compared with V\(_2\)O\(_5\)-NF, the peaks of V\(_6\)V\(_2\)O\(_5\)/PANI shift to lower binding energies, which suggests the existence of low oxidation states of vanadium. The decomposition of V 2p\(_{1/2}\) spectra reveals the percentage of V\(^{3+}\) and V\(^{4+}\) in V\(_6\)V\(_2\)O\(_5\)/PANI (49.7%) is larger than in V\(_2\)O\(_5\)-NF (8.8%), and the average oxidation state of vanadium in V\(_6\)V\(_2\)O\(_5\)/PANI decreases to 4.6, as shown in Figure S3 (Supporting Information). Based on the XRD result that V\(_6\)V\(_2\)O\(_5\)/PANI demonstrates a pure V\(_2\)O\(_5\) phase, it can be concluded that V\(^{3+}\) and V\(^{4+}\) are related to V\(_6\), which engineer the surface of V\(_6\)V\(_2\)O\(_5\)-NF.

For further study, X-ray absorption near-edge structure (XANES) measurements were employed to probe the oxidation states of vanadium in V\(_6\)V\(_2\)O\(_5\)/PANI in bulk, and the commercial V\(_2\)O\(_5\), VO\(_2\) and V\(_2\)O\(_3\) served as empirical standards.\(^{(17)}\) In Figure 1f, the V K-edge XANES spectrum of V\(_6\)V\(_2\)O\(_5\)/PANI presents a modest edge shift to lower photon energies, which corresponds to reduction of the system and suggests the existence of V\(_6\) in V\(_6\)V\(_2\)O\(_5\)/PANI. In addition, the spectrum of V\(_6\)V\(_2\)O\(_5\)/PANI generally agrees with that of V\(_2\)O\(_5\), which reveals the bulk of V atoms remain in V\(_2\)O\(_5\). The fitting result show a smaller concentration of VO (5.4 %) than XPS result (49.7%), confirming the near-surface engineering of V\(_6\) in V\(_6\)V\(_2\)O\(_5\)/PANI. This result is also consistent with XPS and XRD results.

Scanning electron microscopy (SEM) images shows a porous and nanofiber-like structure of V\(_6\)V\(_2\)O\(_5\)/PANI in Figure 2a,b. Transmission electron microscopy (TEM) images display a nanocable structure with an ≈7 nm uniform PANI shell, as shown in Figure 2c,d. High-resolution TEM (HRTEM) image (Figure 2e) demonstrates defects with blurred lattice fringes and dark points. After further characterized by inverse fast Fourier transform (IFFT) in Figure 2f, dislocations are observed in red circles, accompanied with an expanded interplanar spacing ranging from 5.94 to 6.79 Å (standard parameter is 5.76 Å), corresponding to the (020) crystal planes of V\(_2\)O\(_5\).

These dislocations arise from V\(_6\) which induce the skewing of other vanadium atoms around the vacancy sites in V\(_2\)O\(_5\). These dislocations not only show obvious evidence of the generation of VO in V\(_6\)V\(_2\)O\(_5\)/PANI, but also agree with the above XRD, XPS and XANES results. V\(_6\) help to ensure the uniformity of PANI by providing favorable nucleation sites for the polymerization of PANI monomers, limiting the mobility of monomers and restricting the formation and the aggregation of PANI nanoparticles during the polymerization processes, which is also proved in V\(_6\)-modified Co\(_2\)O\(_3\)/graphene.\(^{(18)}\) The uniformity of PANI is further proven by energy-dispersive X-ray spectrometry (EDS) mapping analysis (Figure 2h) and line scan profile (Figure 2i) from high-angle annular dark-field scanning transmission electron microscopy (HADDF-STEM). Based on the results, the interface of V\(_6\)V\(_2\)O\(_5\)/PANI is simultaneously engineered with V\(_6\) and porous PANI coating.

In the polymerization process of PANI, aniline monomers are oxidized and involve electron lost and deprotonation process.\(^{(19)}\) As is known that electron can be taken away from oxygen (O\(_2\)) in V\(_2\)O\(_5\) primitive lattice and then generate V\(_6\) and O\(^{\ldots}\), O\(^{\ldots}\) and H\(^{\ldots}\) will form H\(_2\)O and V\(^{\ldots}\) in V\(_2\)O\(_5\); receives these electrons and obtain V\(^{\ldots}\) and even V\(^{\ldots}\). Therefore, the possible reactions are believed to proceed as follows (Equations (1)–(4))

\[
\begin{align*}
\text{a)} & \quad n \text{CaH}_2\text{NH}_2 - (2n - 2) e^- \rightarrow \text{H(CaH}_2\text{NH})_n \text{H} + (2n - 2) \text{H}^+ \\
\text{b)} & \quad \text{O}^\cdot = \text{V}^\circ + \text{O}^\cdot \\
\text{c)} & \quad 2\text{H}^+ + \text{O}^\cdot \rightarrow \text{H}_2\text{O(g)} \\
\text{d)} & \quad \text{V}^\cdot + e^- \rightarrow \text{V}^\circ \\
\text{e)} & \quad \text{V}^\cdot + e^- \rightarrow \text{V}^\circ \\
\text{f)} & \quad \text{The above reactions can be written as follows}
\end{align*}
\]

\[
\begin{align*}
n\text{CaH}_2\text{NH}_2 + (2n - 2) \text{V}^\circ + (n - 1)\text{O}^\cdot & \rightarrow \text{H(CaH}_2\text{NH})_n \text{H} \\
+ n\text{V}^\circ + \left( n - 1 - \frac{1}{2} m \right) \text{V}^\circ + (n - 1)\text{V}^\circ + (n - 1)\text{H}_2\text{O(g)}
\end{align*}
\]

The cyclic voltammetry (CV) and galvanostatic charge/discharge (GCD) measurements were carried out to evaluate the electrochemical potential of V\(_6\)V\(_2\)O\(_5\)/PANI in a symmetric supercapacitor. The electrolyte is 1 M Na\(_2\)SO\(_4\) aqueous solution. V\(_6\)V\(_2\)O\(_5\)/PANI electrodes show pseudocapacitive behaviors with rectangular-like CV loops (Figure 3a) and symmetric GCD curves (Figure 3b) under different scan rates. No redox peaks are observed because that the fast, reversible, successive multiple redox reactions occur at the electrode surface.\(^{(20)}\) The specific capacitance of V\(_6\)V\(_2\)O\(_5\)/PANI electrode is 523 F g\(^{-1}\) when the current density is 0.5 A g\(^{-1}\). Such an excellent specific
capacitance can be attributed to the addition of Vₐ as well as the porous PANI shell in V₂O₅. For further study, V₂O₅-NF and commercial PANI (Alfa Aesar) were mechanically mixed (noted as V₂O₅/PANI) with the mass ratio from the TG-DSC result, since Vₐ and PANI are simultaneously introduced into V₂O₅. Detail information can be found in Figure S4 (Supporting Information). As shown in Figure 3c, the voltammogram area (5 mV s⁻¹) of V₂O₅/PANI (without Vₐ) is between Vₐ-V₂O₅/PANI and V₂O₅-NF due to the PANI. Consistently, the specific capacitance of V₂O₅/PANI (316 F g⁻¹) is much lower than that of Vₐ-V₂O₅/PANI (523 F g⁻¹), higher than that of V₂O₅-NF (225 F g⁻¹) at 0.5 A g⁻¹ in Figure 3d. The above results directly evidence that the excellent electrochemical performance of Vₐ-V₂O₅/PANI results from the synergy between Vₐ and PANI. Vₐ-V₂O₅/PANI electrodes deliver a higher specific capacitance than V₂O₅/PANI and V₂O₅-NF even at large current density of 10 A g⁻¹, as shown in Figure 3e. In Figure 3f, the energy density of Vₐ-V₂O₅/PANI is 73 W h kg⁻¹, higher than that of V₂O₅/PANI (44 W h kg⁻¹) and V₂O₅-NF (31 W h kg⁻¹), when the power density is 2500 W kg⁻¹.

As the terminally (vanadyl) oxygen has been reported as the easiest site to generate Vₐ in V₂O₅ bulk structure,[21] the following discussion will focus on the Vₐ located at a vanadyl bound oxygen. The Vₐ site viewed along different directions are shown in Figure 4a. With skewing of vanadium atoms, especially around the Vₐ sites, which was obviously observed as dislocations in the above IFFT images, an imbalanced charge distribution would occur in V₂O₅ layer plane, resulting in a positive region in the Vₐ center and a corresponding negatively charged region around Vₐ. As illustrated in Figure 4b, when discharging, an adventitious electric field forms with the direction from the non-Vₐ area to the negatively charged region, and the Coulombic force will attract Na⁺ ions to migrate to the area around the Vₐ. Then, the negatively charged area will be electrically neutral after fully discharged. When charging, the Na⁺ migration will be accelerated by the Coulombic force from the local electric field, whose direction is from the positive region of the Vₐ center to the neutral Na⁺ area. Thus, the ion transfer dynamics is promoted by the Vₐ caused local electric field, which is also founded in other layer-structure electrode materials.[22]

In the Nyquist plots in Figure 4d, Vₐ-V₂O₅/PANI electrode manifests a much smaller electron transfer resistance Rct (3.2 Ω) than V₂O₅/PANI (14.1 Ω) and V₂O₅-NF (18.9 Ω), and Vₐ-V₂O₅/PANI exhibits the largest slope, which suggests enhanced electron transfer kinetics and faster ion diffusion in
Vö-V₂O₅/PANI for redox reactions. This enhancement renders Vö-V₂O₅/PANI excellent electrochemical performance. It is worth noting that, the resistance of V₂O₅/PANI electrode get larger than Vö-V₂O₅/PANI without Vö, while much improved by PANI compared with V₂O₅-NF. Thus, the high electrochemical performance of Vö-V₂O₅/PANI derives from synergistically enhanced kinetics by both rich Vö in the surface of V₂O₅ and the electronically conductive porous PANI coating. As schematically illustrated in Figure 4c, not only do Vö enable fast electron transfer by providing void sites for electron acceptance/donation, but also catalyze the redox reaction at the surface. The expanded interplanar spacing also provide an efficient channel for ionic transport. Moreover, Vö promote the Na⁺ ion transfer dynamics with an adventitious Coulombic force by intrinsically inducing a local electric field in the plane of V₂O₅ (analyzed above). On the other hand, the porous PANI shell serves as the external percolated charge transport pathway in a nanocable nanostructure and accelerate the electron transfer due to its high electrical conductivity.

In Figure 4e, Vö-V₂O₅/PANI electrode delivers 110% of the initial capacitance retention after 20 000 cycles at 10 A g⁻¹, accompanied with a Coulombic efficiency of nearly 100%. The corresponding GCD curves of the first 5 cycles and the last 5 cycles suggest no capacitance degradation after cycling. SEM and TEM images (Figure S5a–c, Supporting Information) display a well-preserved nanocable structure for Vö-V₂O₅/PANI electrode after cycling. In HRTEM image (Figure S5d, Supporting Information), although the PANI shell changes slightly with the thickness ranging from ≈4 to ≈7 nm, the PANI coating remains tightly anchored to V₂O₅-NF due to the in situ polymerization of PANI, which proves the excellent structural integrity and stability of Vö-V₂O₅/PANI; the long cycling durability is attributed to the following. First, the porous PANI shell enhances the charge transfer kinetics by providing external...
percolated charge transport pathway and enlarging the surface area for high utilization of active materials, similar results have also been reported in literature.[23] PANI coating may also prevent or retard vanadium dissolution into electrolyte, and buffers the volume expansion/contraction of V2O5 during charge/discharge process, as suggested in literature[8,24]. The above advantages of PANI are beneficial for the structural stability of V2O5. Second, V0 can balance the internal stress and electrostatic repulsion of adjacent layers, stabilizing the layer structure of V2O5.[25] For the increasing capacitance, with V0 distributed at the surface of V2O5-NF, the electric field for charging/discharging may promote V0 to migrate and diffuse, leading to more V5+ at the surface region for redox reactions.[26] It is also possible that V0-V2O5/PANI are electro-activated by electrolyte and then results in an increased specific capacitance after a long time of cycling.[33] This cyclability is superior to other supercapacitors based on V2O5/PANI nanowires (92% after 5000 cycles),[14] V2O5/graphene/MWCNT (82.9% after 1000 cycles),[27] and core-shell V2O5/PPy (82.7% after 2000 cycles).[28]

3. Conclusions
Local electric field has been induced in the shallow layer of V0-V2O5/PANI nanocables in a one-step oxidative polymerization process. In the resultant V0-V2O5/PANI nanocables, caused by a lopsided charge distribution around V0, the local electric field provides Coulombic forces to promote charge transport of in V2O5-NF. Simultaneously, the ≈7 nm porous PANI layer serves as external percolated transport pathway for charge during the charging and discharging processes. Therefore, charge transfer dynamics of V0-V2O5/PANI electrode is synergistically enhanced by V0 and porous PANI shells, resulting in an excellent specific capacitance at 523 F g⁻¹ and a high energy density of 73 W h kg⁻¹ at the power density of 10 A g⁻¹.

Figure 4. a) The vacancy site in V2O5 structure viewed along the [001] and [010] directions. b) Schematic illustration of charge transfer behavior around the V0 region by forming local electric field (E). c) The enhanced charge transfer kinetics mechanism of V0-V2O5/PANI due to the synergy of V0 and PANI. d) Nyquist plots of V0-V2O5/PANI, mechanically mixed V2O5/PANI and V2O5-NF based supercapacitors. e) Cycling performance and corresponding Coulombic efficiency of V0-V2O5/PANI at 10 A g⁻¹ (inset shows the first 5 and the last 5 GCD curves at 10 A g⁻¹).
2500 W kg\(^{-1}\). V\(_{6}\)-V\(_2\)O\(_5\)/PANI show a long cycling life with 110% of initial capacitance remained after 20,000 cycles. This work paves an effective way to enhance the electrochemical properties of transmission metal oxides for next-generation energy storage devices.

4. Experimental Section

**Synthesis of V\(_2\)O\(_5\)-NF**: V\(_2\)O\(_5\)-NF was prepared with the same method as reported.\(^{[30]}\) Briefly, V\(_2\)O\(_5\) powder, benzyl alcohol and isopropanol (a molar ratio of 1:4:40) were mixed and kept at 90 °C under condensate reflux for 4 h. After filtration, the filtrate was concentrated to 1/3 volume by heating reflux at 110 °C. Then, 10 mL deionized water was added into 15 mL above vanadium oxide oligomers under vigorous stirring and kept at 50 °C for 2 days. After solvent replacement, freeze drying and heating in air at 300 °C for 3 h, V\(_2\)O\(_5\)-NF was obtained.

**Synthesis of V\(_6\)-V\(_2\)O\(_5\)/PANI nanocables**: V\(_6\)-V\(_2\)O\(_5\)-NF was pretreated with hydrochloric acid (36 wt%, 0.5 mL) in vacuum at 25 °C. 0.5 mL aniline monomers was used and vaporized aniline monomers deposited and polymerized on the surface of V\(_2\)O\(_5\)-NF at 80 °C in vacuum, generating V\(_6\) in the shallow layer of V\(_2\)O\(_5\)-NF and forming a PANI coating. The sample was dried in 120 °C in vacuum for 12 h. The yellow V\(_2\)O\(_5\)-NF turns dark blue (Figure S1, Supporting Information), which indicates the successful fabrication of V\(_6\)-V\(_2\)O\(_5\)/PANI.

**Chemical and Structural Characterizations**: The composition of samples was identified with Fourier transform infrared spectroscopy (Bruker-TENSOR27 FTIR spectrometer) from 400 to 4000 cm\(^{-1}\), and with Thermogravimetric and differential scanning calorimetry analyses on SDT Q600 from 25 to 800 °C at a heating rate of 10 °C/min (flowing air). Nitrogen adsorption isotherms were conducted on an Autosorb-1 (Quantachrome) analyzer. The crystalline information of as-prepared samples was measured by X-ray diffractometer (Bruker D8 Advance, Germany) using a Rigaku D/max-C diffractometer and Cu K\(_\alpha\) (\(\lambda = 0.15406 \text{ nm}\)) radiation. The surficial vanadium oxidation states of all sample were examined by X-ray photoelectron spectroscopy and the spectrum was obtained with Mg K\(_\alpha\) radiation (\(h\nu = 1253.6 \text{ eV}\)) in the PHI-5,000C ESCA system. The concentration of each oxidation state of vanadium cations was estimated from the corresponding peak area percentage. The overall vanadium oxidation states of the samples were examined by X-ray absorption near-edge structure measurements in the vanadium K-edge using laboratory-based instrumentation (University of Washington),\(^{[30]}\) and analyzed with a reported methodology.\(^{[31]}\) Fitting was performed in Mathematica with the energy from 5460 to 5490 eV, using the function NonlinearModelFit through a linear combination of the spectra of reference compounds. The fitting was constrained that the component of each oxide compound be between null and unity and the sum of all components be unity. The morphologies of all samples were characterized by field emission scanning electron microscopy (FESEM, S-4800, Japan) and transmission electron microscopy (JEOLR2100, Japan). Raman spectra (Jobin-Yvon HR8000) were recorded from 100 to 2000 cm\(^{-1}\) using a 514 nm argon ion laser.

**Electrochemical Characterizations**: The electrodes were prepared by mixing active materials, acetylene black and poly(vinylidene fluoride) (PVDF) in N-methylpyrrolidone (NMP) with a mass ratio of 80:10:10. The slurry was painted onto a graphite paper current collector and dried under vacuum at 120 °C overnight. A symmetric-electrode test cell and 1 M Na\(_2\)SO\(_4\) solution were used. Mass loading of each electrode is about 1 mg cm\(^{-2}\). Cyclic voltammogram and galvanostatic charge/discharge and electrochemical impedance spectroscopy (EIS) were performed on a CH660C (Chenhua) electrochemical working station with the voltage from −1 to 1 V\(^{[10,12,13]}\). The scan rates of CV are 5, 10, 25, 50, and 100 mV s\(^{-1}\), and the current densities of GCD are 0.5, 1, 2.5, 5, and 10 A g\(^{-1}\). The EIS was carried out in the frequency range 0.01 Hz to 100 kHz with an AC voltage amplitude of 5 mV. The specific capacitance of each electrode (C, F g\(^{-1}\)) was calculated from the discharging process in GCD curves according to the equation $C = \Delta t / (m\Delta V)$, where $\Delta t$ is the constant discharging current, $m$ is the total mass of each electrode, $\Delta t$ is the discharging duration, and $\Delta V$ is the voltage window (1 V). The equations of $E = (1/2)\Delta(CV)^2/3600$ and $P = E/\Delta t$ were used to calculate energy density (E, W h kg\(^{-1}\)) and power density (P, W kg\(^{-1}\)) in Ragone plots, respectively.\(^{[34]}\)

**Supporting Information**

Supporting Information is available from the Wiley Online Library or from the author.

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**Conflict of Interest**

The authors declare no conflict of interest.

**Keywords**

interfaces, local electric fields, polyaniline, supercapacitors, vanadium pentoxide

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